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ON Semiconductor NJVMJD2955T4G

For any questions, you can email us directly: sales@integrated-circuit.com



MJD2955 (PNP), **MJD3055 (NPN)**

Complementary Power Transistors

DPAK for Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Electrically Similar to MJE2955 and MJE3055
- High Current Gain-Bandwidth Product
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	60	Vdc
Collector-Base Voltage	V _{CB}	70	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current	I _C	10	Adc
Base Current	I _B	6	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D [†]	20 0.16	W W/°C
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- †Safe Area Curves are indicated by Figure 1. Both limits are applicable and must be observed.
- 1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

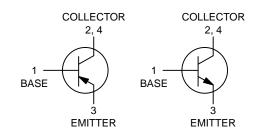


ON Semiconductor®

http://onsemi.com

SILICON **POWER TRANSISTORS** 10 AMPERES 60 VOLTS, 20 WATTS

COMPLEMENTARY





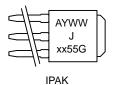


CASE 369C STYLE 1

IPΔK CASE 369D STYLE 1

MARKING DIAGRAMS





DPAK

= Assembly Location

= Year $\mathsf{W}\mathsf{W}$ = Work Week = Device Code Jxx55

> x = 29 or 30= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Datasheet of NJVMJD2955T4G - TRANS PNP 60V 10A DPAK-4

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MJD2955 (PNP), MJD3055 (NPN)

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	71.4	°C/W

^{2.} These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Min	Max	Unit
1			
V _{CEO(sus)}	60	_	Vdc
I _{CEO}	_	50	μAdc
ICEX	<u>-</u>	0.02	mAdc
Ісво	- -	0.02	mAdc
I _{EBO}	-	0.5	mAdc
•		•	
h _{FE}	20 5	100	-
V _{CE(sat)}	- -	1.1	Vdc
V _{BE(on)}	-	1.8	Vdc
-		•	•
f _T	2	_	MHz
	VCEO(sus) ICEO ICEX ICBO IEBO VCE(sat) VBE(on)	VCEO(sus) 60 ICEO - ICEX - ICBO - ICBO - ICBO - VCE(sat) - VBE(on) -	VCEO(sus) 60 - ICEO - 50 ICEX - 0.02 - 2 ICBO - 0.02 - 2 IEBO - 0.5 Note Set 100 The set 1000 The set

^{3.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.



1.4

1.2

8.0

0.4

0.2

V, VOLTAGE (VOLTS)

 $T_J=25^{\circ}C$

 $V_{BE(sat)} @ I_C/I_B = 10$

 V_{BE} @ $V_{CE} = 2 V$

 $V_{CE(sat)} @ I_C/I_B = 10$

0.5

0.2 0.3

MJD2955 (PNP), MJD3055 (NPN)

TYPICAL CHARACTERISTICS

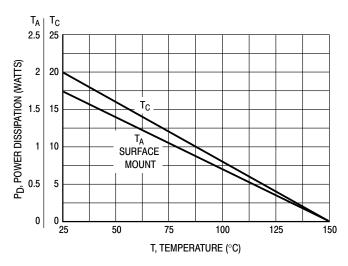


Figure 1. Power Derating

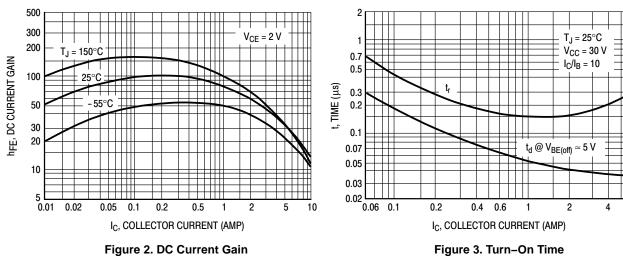
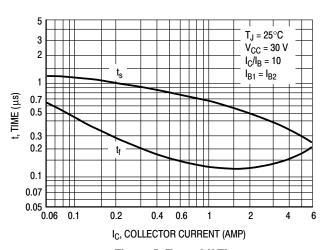


Figure 2. DC Current Gain



I_C, COLLECTOR CURRENT (AMP) Figure 4. "On" Voltages, MJD3055

Figure 5. Turn-Off Time

10

Datasheet of NJVMJD2955T4G - TRANS PNP 60V 10A DPAK-4

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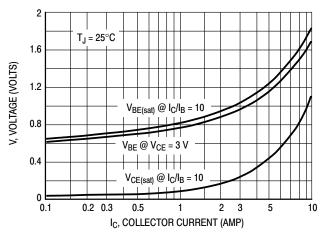
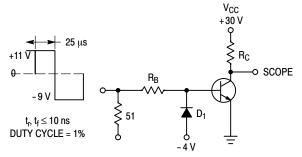


Figure 6. "On" Voltages, MJD2955



R_B and R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS

D₁ MUST BE FAST RECOVERY TYPE, eg: 1N5825 USED ABOVE I_B \approx 100 mA MSD6100 USED BELOW I_B \approx 100 mA

Figure 7. Switching Time Test Circuit

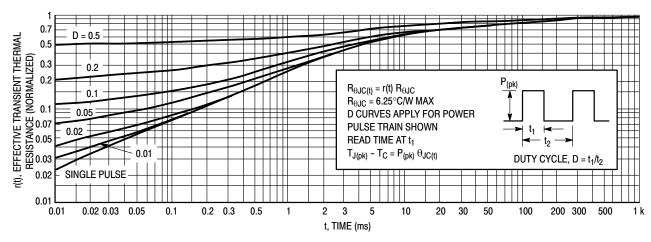


Figure 8. Thermal Response

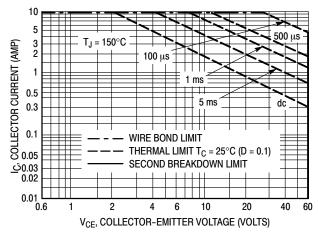


Figure 9. Maximum Forward Bias Safe Operating Area

Forward Bias Safe Operating Area Information

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 9 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



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MJD2955 (PNP), MJD3055 (NPN)

ORDERING INFORMATION

Device	Package Type	Package	Shipping [†]
MJD2955G	DPAK (Pb-Free)	369C	75 Units / Rail
MJD2955-1G	IPAK (Pb-Free)	369D	75 Units / Rail
MJD2955T4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel
NJVMJD2955T4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel
MJD3055G	DPAK (Pb-Free)	369C	75 Units / Rail
MJD3055T4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel
NJVMJD3055T4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

Datasheet of NJVMJD2955T4G - TRANS PNP 60V 10A DPAK-4

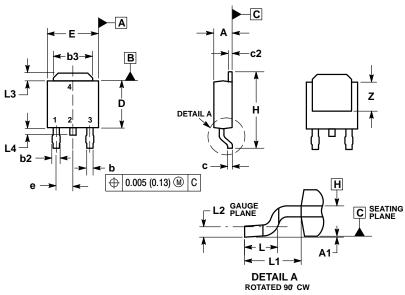
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MJD2955 (PNP), MJD3055 (NPN)

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

CASE 369C ISSUE D



NOTES

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: INCHES.

 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.

 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.

 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.

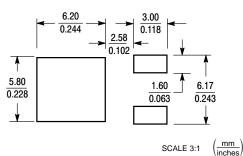
 6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

•	D/ (I CIVIC / (/
	PLANE H.

	INCHES		MILLIM	IETERS		
DIM	MIN	MAX	MIN	MAX		
Α	0.086	0.094	2.18	2.38		
A1	0.000	0.005	0.00	0.13		
b	0.025	0.035	0.63	0.89		
b2	0.030	0.045	0.76	1.14		
b3	0.180	0.215	4.57	5.46		
С	0.018	0.024	0.46	0.61		
c2	0.018	0.024	0.46	0.61		
D	0.235	0.245	5.97	6.22		
E	0.250	0.265	6.35	6.73		
е	0.090	BSC	2.29	BSC		
Н	0.370	0.410	9.40	10.41		
L	0.055	0.070	1.40	1.78		
L1	0.108 REF		2.74	4 REF		
L2	0.020 BSC		0.51	BSC		
L3	0.035	0.050	0.89	1.27		
L4		0.040		1.01		
Z	0.155		3.93			

- STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



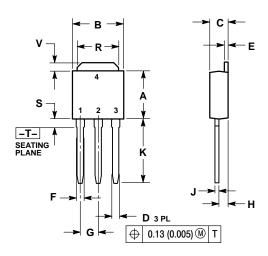
Datasheet of NJVMJD2955T4G - TRANS PNP 60V 10A DPAK-4

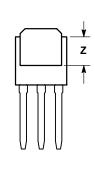
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MJD2955 (PNP), MJD3055 (NPN)

PACKAGE DIMENSIONS

IPAK CASE 369D ISSUE C





IOTES.

- DIMENSIONING AND TOLERANCING PER
 ANSI Y14 5M 1982
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIM	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.35	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.090 BSC		2.29	BSC	
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.350	0.380	8.89	9.65	
R	0.180	0.215	4.45	5.45	
S	0.025	0.040	0.63	1.01	
٧	0.035	0.050	0.89	1.27	
Z	0.155		3.93		

STYLE 1:

IN 1. BASE

- 2. COLLECTOR 3. EMITTER
- 3. EMITTER 4. COLLECTOR

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